

RGTH00TS65

650V 50A Field Stop Trench IGBT

V_{CES}	650V
I _{C(100°C)}	50A
V _{CE(sat) (Typ.)}	1.6V
P_D	277W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

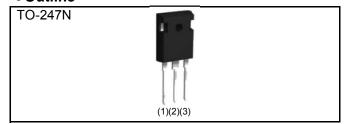
PFC

UPS

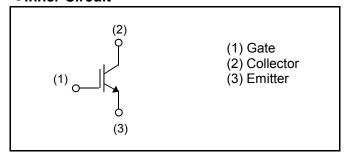
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Typo	Tape Width (mm)	-
Type Basic Ordering Unit (450
	Packing code	C11
	Marking	RGTH00TS65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Callactor Current	T _C = 25°C	I _C	85	А
Collector Current	T _C = 100°C	I _C	50	А
Pulsed Collector Current		I _{CP} *1	200	А
$T_C = 25^{\circ}C$		P _D	277	W
Power Dissipation	T _C = 100°C	P _D	138	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{jmax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
raiametei		Min.	Тур.	Max.	
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.54	°C/W

ullet IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
r ai ainetei	Symbol Conditions		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	1	1	V
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	1	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 34.7 \text{mA}$	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_C = 50A$, $V_{GE} = 15V$ $T_j = 25$ °C $T_i = 175$ °C	-	1.6	2.1	V
		1j- 175 C	-	2.1	-	

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min. Typ		Max.	Utill
Input Capacitance	C _{ies}	V _{CE} = 30V	-	2740	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	106	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	43	-	
Total Gate Charge	Q_g	V _{CE} = 300V	-	94	-	
Gate - Emitter Charge	Q _{ge}	I _C = 50A	-	22	-	nC
Gate - Collector Charge	Q _{gc}	V _{GE} = 15V	-	31	-	
Turn - on Delay Time	t _{d(on)}	I _C = 50A, V _{CC} = 400V	-	39	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	63	-	no
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	143	-	ns
Fall Time	t _f	Inductive Load	-	50	-	
Turn - on Delay Time	t _{d(on)}	I _C = 50A, V _{CC} = 400V	-	39	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	63	-	no
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	159	-	ns
Fall Time	t _f	Inductive Load	-	62	-	
		I _C = 200A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650V, V_{GE} = 15V$	FU	LL SQUA	RE	-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

•Electrical Characteristic Curves

Fig.1 Power Dissipation vs. Case Temperature

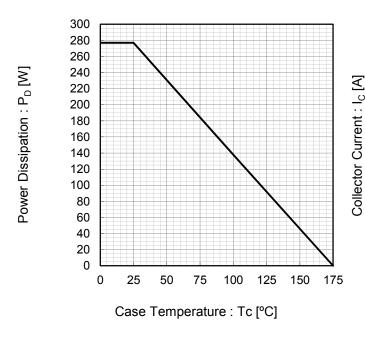


Fig.2 Collector Current vs. Case Temperature

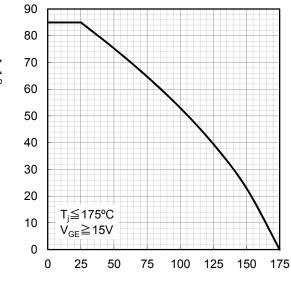
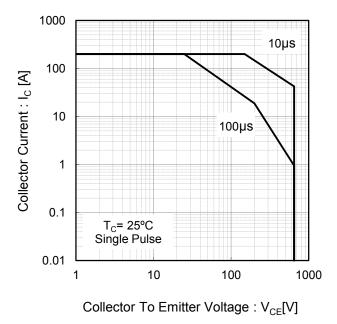


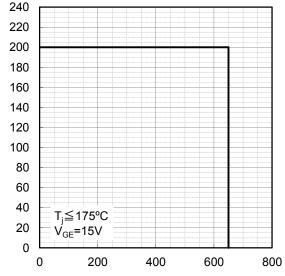
Fig.3 Forward Bias Safe Operating Area



Collector Current : I_C [A]

Fig.4 Reverse Bias Safe Operating Area

Case Temperature : Tc [°C]



Collector To Emitter Voltage : $V_{CE}[V]$

Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

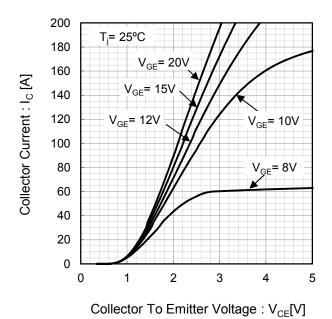
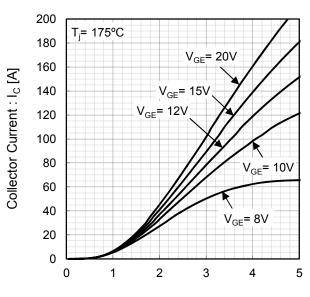


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V_{CE}[V]

Fig.7 Typical Transfer Characteristics

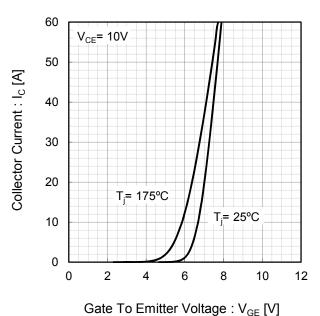
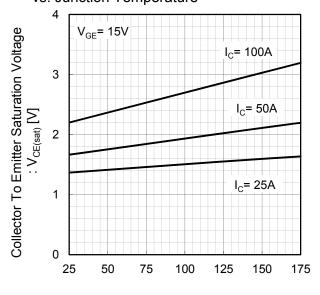


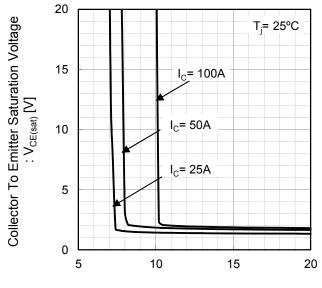
Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

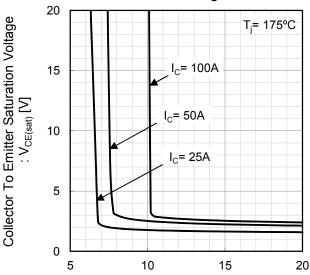
Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



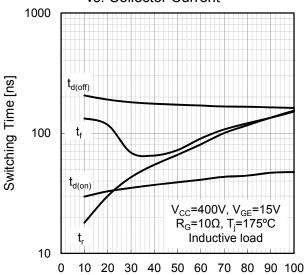
Gate To Emitter Voltage : V_{GE} [V]

Fig. 10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



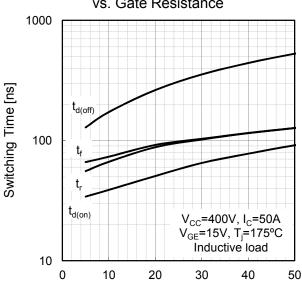
Gate To Emitter Voltage : $V_{GE}[V]$

Fig.11 Typical Switching Time
vs. Collector Current



Collector Current : I_C [A]

Fig.12 Typical Switching Time vs. Gate Resistance



Gate Resistance : $R_G[\Omega]$

• Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current

10 E_{off} 0.1 E_{off} $V_{CC}=400V, V_{GE}=15V$ $E_{G}=10\Omega, T_{J}=175^{\circ}C$ Inductive load

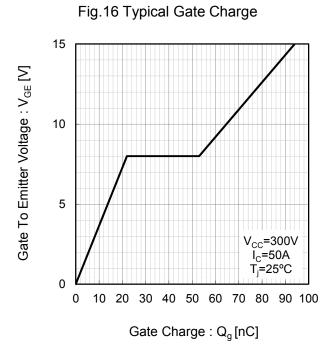
0 10 20 30 40 50 60 70 80 90 100

Collector Current : I_{C} [A]

vs. Gate Resistance 10 Switching Energy Losses [mJ] $\mathsf{E}_{\mathsf{off}}$ 1 0.1 V_{CC}=400V, I_C=50A V_{GE}=15V, T_j=175°C Inductive load 0.01 10 20 0 30 40 50 Gate Resistance : $R_G[\Omega]$

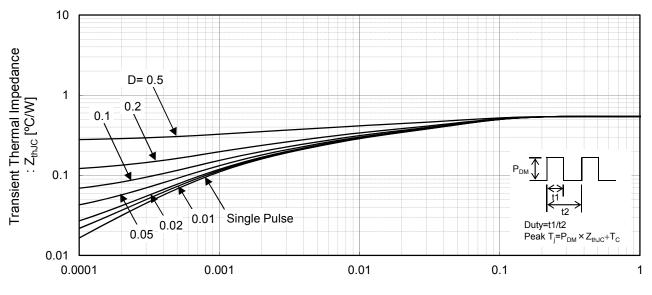
Fig.14 Typical Switching Energy Losses

Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz $V_{GE}=0V$ T_i=25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : V_{CE}[V]



•Electrical Characteristic Curves

Fig.17 IGBT Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

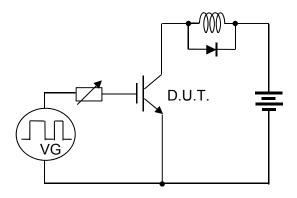


Fig.18 Inductive Load Circuit

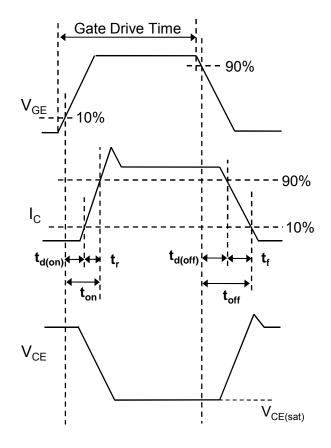


Fig.19 Inductive Load Waveform

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RGTH00TS65 - Web Page

Distribution Inventory

Part Number	RGTH00TS65
Package	TO-247N
Unit Quantity	450
Minimum Package Quantity	450
Packing Type	Bulk
Constitution Materials List	inquiry
RoHS	Yes